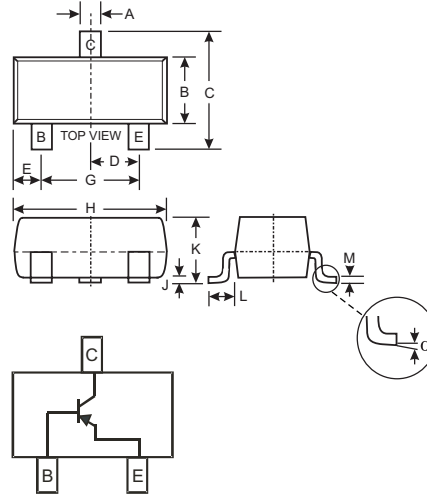


**Features**

- Epitaxial Planar Die Construction
- Complementary NPN Type Available (DN350T05)
- Ideal for Medium Power Amplification and Switching
- **Lead Free By Design/RoHS Compliant (Note 2)**
- **"Green Device" (Note 3)**
- **Qualified to AEC-Q101 Standards for High Reliability**

**Mechanical Data**

- Case: SOT-23
- Case Material: Molded Plastic. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C
- Terminal Connections: See Diagram
- Terminals: Finish — Matte Tin Finish annealed over Alloy 42 leadframe. Solderable per MIL-STD-202, Method 208
- Marking (See Page 2): K3U
- Ordering & Date Code Information: See Page 2
- Weight: 0.008 grams (approximate)



SOT-23		
Dim	Min	Max
A	0.37	0.51
B	1.20	1.40
C	2.30	2.50
D	0.89	1.03
E	0.45	0.60
G	1.78	2.05
H	2.80	3.00
J	0.013	0.10
K	0.903	1.10
L	0.45	0.61
M	0.085	0.180
$\alpha$	0°	8°
All Dimensions in mm		

**Maximum Ratings** @  $T_A = 25^\circ\text{C}$  unless otherwise specified

Characteristic	Symbol	DP350T05	Unit
Collector-Base Voltage	$V_{CBO}$	-350	V
Collector-Emitter Voltage	$V_{CEO}$	-350	V
Emitter-Base Voltage	$V_{EBO}$	-5.0	V
Continuous Collector Current (Note 1)	$I_C$	-500	mA
Power Dissipation (Note 1)	$P_d$	300	mW
Thermal Resistance, Junction to Ambient (Note 1)	$R_{\theta JA}$	417	$^\circ\text{C/W}$
Operating and Storage and Temperature Range	$T_j, T_{STG}$	-55 to +150	$^\circ\text{C}$

- Notes:
1. Device mounted on FR-4 PCB, 1 inch x 0.85 inch x 0.062 inch; pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at <http://www.diodes.com/datasheets/ap02001.pdf>.
  2. No purposefully added lead.
  3. Diodes Inc.'s "Green" policy can be found on our website at [http://www.diodes.com/products/lead\\_free/index.php](http://www.diodes.com/products/lead_free/index.php).

## Electrical Characteristics @ T<sub>A</sub> = 25°C unless otherwise specified

Characteristic	Symbol	Min	Max	Unit	Test Condition
<b>OFF CHARACTERISTICS (Note 4)</b>					
Collector-Base Breakdown Voltage	V <sub>(BR)CBO</sub>	-350	—	V	I <sub>C</sub> = -100μA, I <sub>E</sub> = 0
Collector-Emitter Breakdown Voltage	V <sub>(BR)CEO</sub>	-350	—	V	I <sub>C</sub> = -1.0mA, I <sub>B</sub> = 0
Emitter-Base Breakdown Voltage	V <sub>(BR)EBO</sub>	-5.0	—	V	I <sub>E</sub> = -10μA, I <sub>C</sub> = 0
Collector Cutoff Current	I <sub>CBO</sub>	—	-50	nA	V <sub>CB</sub> = -200V, I <sub>E</sub> = 0
Collector Cutoff Current	I <sub>EBO</sub>	—	-50	nA	V <sub>CE</sub> = -3.0V, I <sub>C</sub> = 0
<b>ON CHARACTERISTICS (Note 4)</b>					
DC Current Gain	h <sub>FE</sub>	20	—	—	I <sub>C</sub> = -1.0mA, V <sub>CE</sub> = -10V I <sub>C</sub> = -10mA, V <sub>CE</sub> = -10V I <sub>C</sub> = -30mA, V <sub>CE</sub> = -10V I <sub>C</sub> = -50mA, V <sub>CE</sub> = -10V I <sub>C</sub> = -100mA, V <sub>CE</sub> = -10V
		30	—		
		30	200		
		20	200		
		15	—		
Collector-Emitter Saturation Voltage	V <sub>CE(SAT)</sub>	—	-0.30	V	I <sub>C</sub> = -10mA, I <sub>B</sub> = -1.0mA I <sub>C</sub> = -20mA, I <sub>B</sub> = -2.0mA I <sub>C</sub> = -30mA, I <sub>B</sub> = -3.0mA I <sub>C</sub> = -50mA, I <sub>B</sub> = -5.0mA
		—	-0.35		
		—	-0.50		
		—	-1.0		
Base-Emitter Saturation Voltage	V <sub>BE(SAT)</sub>	—	-0.75	V	I <sub>C</sub> = -10mA, I <sub>B</sub> = -1.0mA I <sub>C</sub> = -20mA, I <sub>B</sub> = -2.0mA I <sub>C</sub> = -30mA, I <sub>B</sub> = -3.0mA
		—	-0.85		
		—	-0.90		
Base-Emitter On Voltage	V <sub>BE(ON)</sub>	—	-2.0	V	I <sub>C</sub> = -100mA, V <sub>CE</sub> = -10V
<b>SMALL SIGNAL CHARACTERISTICS</b>					
Output Capacitance	C <sub>obo</sub>	—	7.0	pF	V <sub>CB</sub> = -20V, f = 1.0MHz, I <sub>E</sub> = 0
Transition Frequency	f <sub>T</sub>	50	—	MHz	V <sub>CE</sub> = -10V, I <sub>C</sub> = -20mA

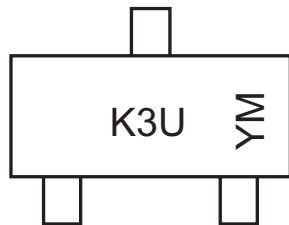
Note: 4. Short duration test pulse used to minimize self-heating effect.

## Ordering Information (Note 5)

Device	Packaging	Shipping
DP350T05-7	SOT-23	3000/Tape & Reel

Note: 5. For Packaging Details, go to our website at <http://www.diodes.com/datasheets/ap02007.pdf>.

## Marking Information

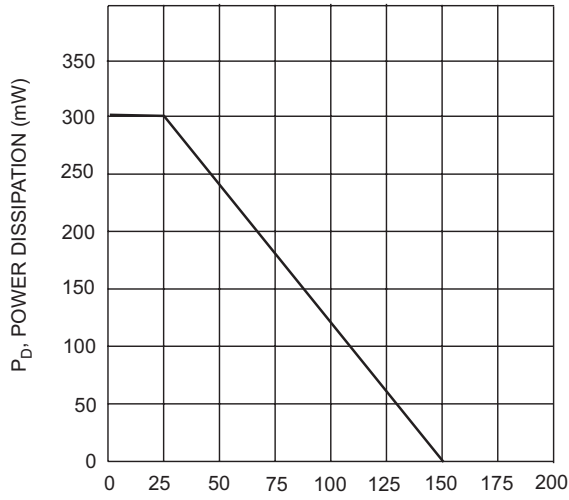


K3U = Product Type Marking Code  
 YM = Date Code Marking  
 Y = Year ex: S = 2005  
 M = Month ex: 9 = September

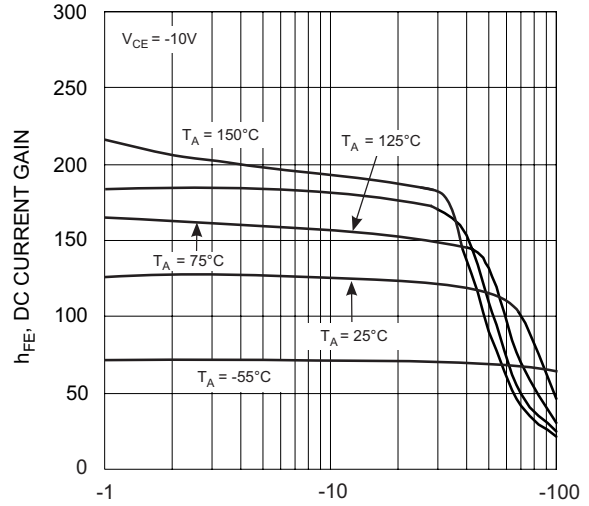
Date Code Key

Year	2005	2006	2007	2008	2009
Code	S	T	U	V	W

Month	Jan	Feb	March	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	O	N	D



$T_A$ , AMBIENT TEMPERATURE (°C)  
Fig. 1, Max Power Dissipation vs Ambient Temperature



$I_C$ , COLLECTOR CURRENT (mA)  
Fig. 2, DC Current Gain vs. Collector Current

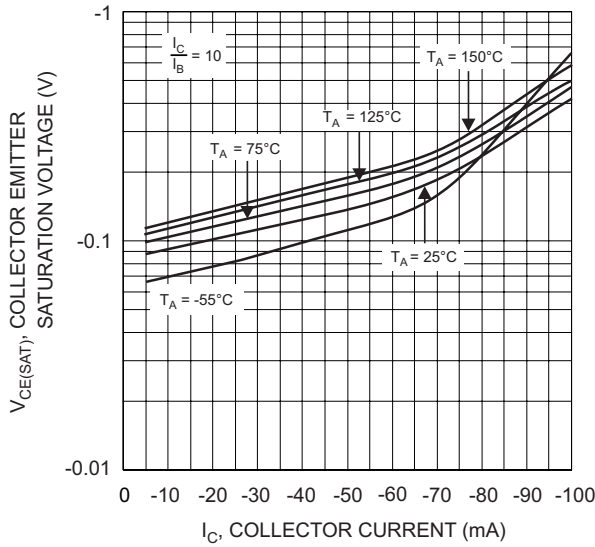


Fig. 3, Collector-Emitter Saturation Voltage vs Collector Current

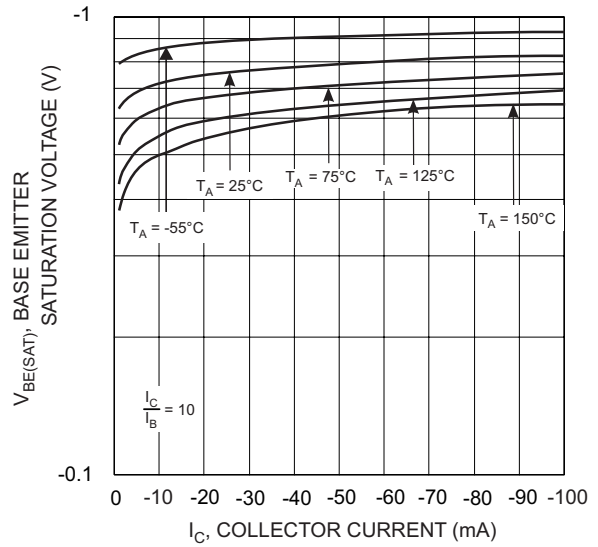


Fig. 4, Base Emitter Saturation Voltage vs Collector Current

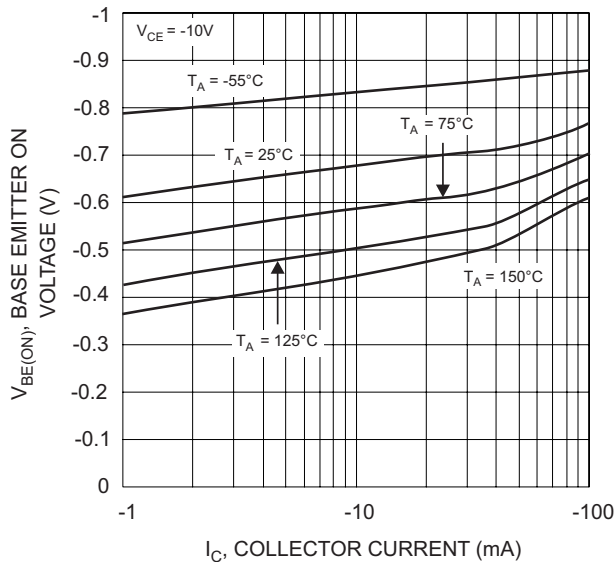


Fig. 5, Base-Emitter On Voltage vs. Collector Current

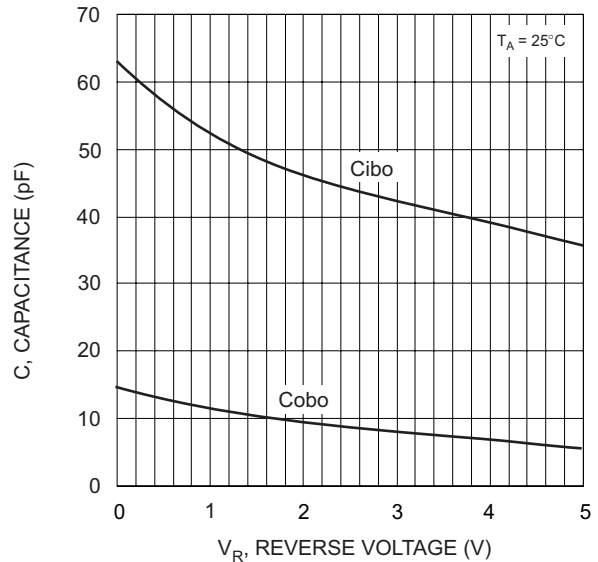


Fig. 6, Capacitance vs. Reverse Voltage